

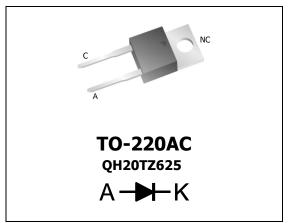
# **QH20TZ625 Qspeed**<sup>™</sup> Family

625 V, 20 A H-Series PFC Diode

# **Product Summary**

${ m I}_{\sf F(AVG)}$	20	Α
$V_{RRM}$	625	V
Q <sub>RR</sub> (Typ at 125 °C)	140	nC
I <sub>RRM</sub> (Typ at 125 °C)	5.0	Α
Softness t <sub>B</sub> /t <sub>A</sub> (Typ at 125 °C)	0.4	

## **Pin Assignment**



# **RoHS Compliant**

Package uses Lead-free plating and Green mold compound. Halogen free per IEC 61249-2-21.

# **General Description**

This device has the lowest  $Q_{RR}$  of any 625 V silicon diode. Its recovery characteristics increase efficiency, reduces EMI and eliminates snubbers. Replaces SiC diodes for similar efficiency performance in high switching frequency applications.

# **Applications**

- Power Factor Correction boost diode
- Server power supplies
- Motor drive circuits
- DC-AC inverters
- · Output rectifier

## **Features**

- •
- High dI<sub>F</sub>/dt capable (1000 A / μs)
- Soft recovery

## **Benefits**

- Increases efficiency
  - Eliminates need for snubber circuits
  - Reduces EMI filter component size & count
- Enables extremely fast switching

# **Absolute Maximum Ratings**

Absolute maximum ratings are the values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Symbol	Parameter	Conditions	Rating	Units
$V_{RRM}$	Peak repetitive reverse voltage	T <sub>J</sub> = 25 °C	625	V
$I_{F(AVG)}$	Average forward current	T <sub>J</sub> = 150 °C, T <sub>C</sub> = 42 °C	20	Α
I <sub>FSM</sub> Non-repetitive peak surge current 6		60 Hz, ½ cycle, T <sub>C</sub> = 25 °C	105	Α
I <sub>FSM</sub> Non-repetitive peak surge current $\frac{1}{2}$ cycle of t = 28		$1/2$ cycle of t = 28 $\mu$ s Sinusoid, $T_C$ = 25 °C	350	Α
T <sub>J</sub>	Operating junction temperature range		-55 to 150	°C
T <sub>STG</sub>	Storage temperature		-55 to 150	°C
	Lead soldering temperature	Leads at 1.6 mm from case, 10 sec	300	°C
$V_{ISOL}$	Isolation voltage (leads-to-tab)	AC, TO-220	2500	V
$P_D$	Power dissipation	T <sub>C</sub> = 25 °C	60	W

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# **Thermal Resistance**

Symbol	Resistance from:	Conditions	Rating	Units
$R_{\theta JA}$	Junction to ambient	TO-220	62	°C/W
$R_{ heta JC}$	Junction to case		2.1	°C/W

Electrical Specifications at  $T_J = 25$  °C (unless otherwise specified)

Symbol	Parameter	Conditions		Min	Тур	Max	Units
DC Chara	DC Characteristics						
$I_R$	Reverse current	V <sub>R</sub> = 625 V, T <sub>J</sub> = 25 °C 250		250	μΑ		
1R	Reverse current	$V_R = 625 \text{ V}, T_J = 125 ^{\circ}$	C	-	3	-	mA
V	Forward voltage	$I_F = 20 \text{ A}, T_J = 25 ^{\circ}\text{C}$		-	2.65	3.15	V
V <sub>F</sub>	Forward voltage	$I_F = 20 \text{ A}, T_J = 150 ^{\circ}\text{C}$	I <sub>F</sub> = 20 A, T <sub>J</sub> = 150 °C		2.35	-	V
C <sub>J</sub>	Junction capacitance	V <sub>R</sub> = 10 V, 1 MHz	V <sub>R</sub> = 10 V, 1 MHz		92	-	pF
Dynamic	Characteristics			·	-	-	
_	D	dI/dt = 200 A/μs	T₃ = 25 °C	-	26.5	-	ns
t <sub>RR</sub>	Reverse recovery time	$V_R = 400 \text{ V}, I_F = 20 \text{ A}$	T <sub>J</sub> = 125 °	C -	41.3	-	ns
0	Devenue necessors change	dI/dt = 200 A/μs	T <sub>J</sub> = 25 °C	-	51	80	nC
$Q_{RR}$	Reverse recovery charge	$V_R = 400 \text{ V}, I_F = 20 \text{ A}$	T <sub>J</sub> = 125 °	С -	140	-	nC
т	Maximum reverse	dI/dt =200 A/μs	T <sub>J</sub> = 25 °C	-	3	4	Α
$I_{RRM}$	recovery current	$V_R = 400 \text{ V}, I_F = 20 \text{ A}$	T <sub>J</sub> = 125 °	C -	5.0	-	Α
	Softness factor = $\frac{t_B}{t_A}$	dI/dt = 200 A/μs	T <sub>J</sub> = 25 °C	-	0.7	-	
S		$V_R = 400 \text{ V}, I_F = 20 \text{ A}$ $T_J = 125$		C -	0.4	-	

**Note to component engineers**: H-Series diodes employ Schottky technologies in their design and construction. Therefore, Component Engineers should plan their test setups to be similar to those for traditional Schottky test setups. (For additional details, see Application Note AN-300.)

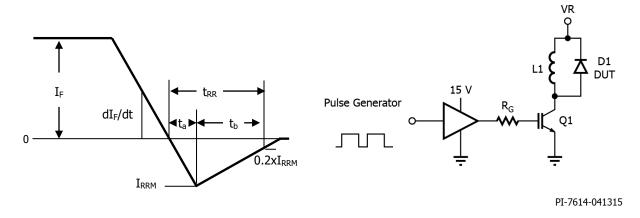
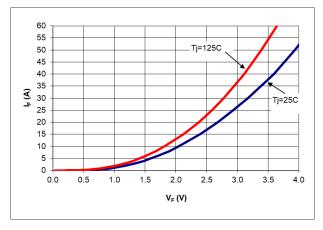


Figure 1. Reverse Recovery Definitions

Figure 2. Reverse Recovery Test Circuit

# Electrical Specifications at $T_1 = 25$ °C (unless otherwise specified)



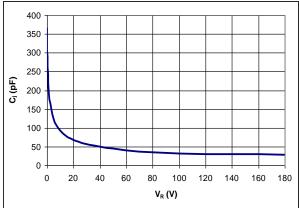
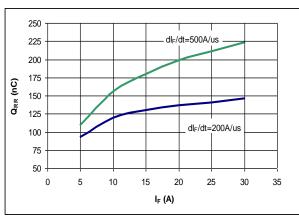


Figure 3. Typical I<sub>F</sub> vs V<sub>F</sub>

Figure 4. Typical C<sub>j</sub> vs V<sub>R</sub>



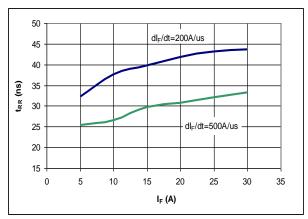
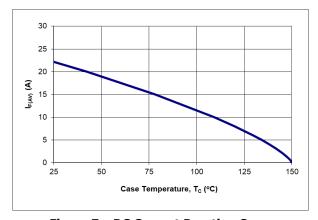


Figure 5. Typical  $Q_{RR}$  vs  $I_F$  at  $T_J = 125$  °C

Figure 6. Typical  $t_{RR}$  vs  $I_F$  at  $T_J = 125$  °C



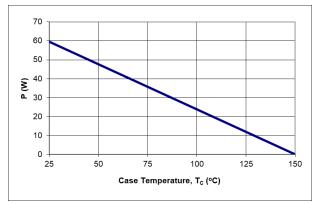


Figure 7. DC Current Derating Curve

Figure 8. Power Derating Curve



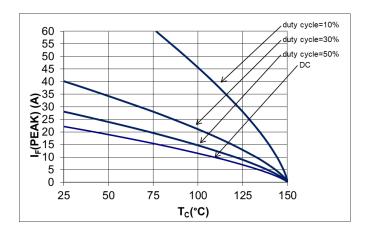


Figure 9.  $I_F(PEAK)$  vs  $T_C$ , f = 70 kHz

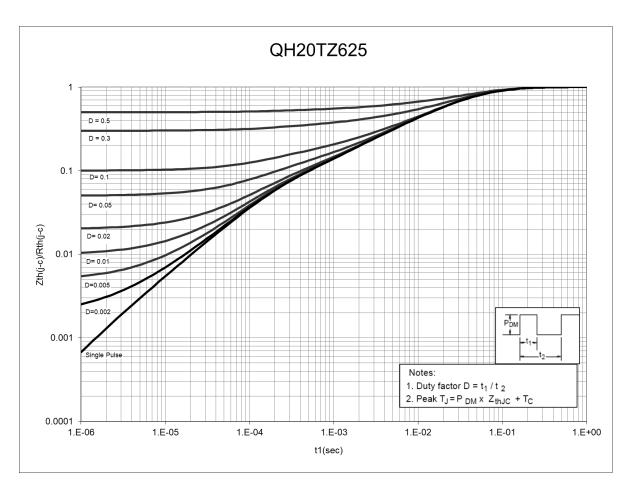
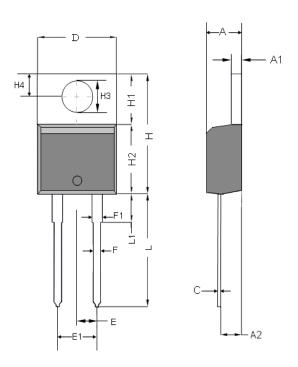


Figure 10. Normalized Maximum Transient Thermal Impedance



# **Dimensional Outline Drawings**

TO-220AC



	Millimeters		
Dim	MIN MAX		
A	4.32	4.70	
<b>A1</b>	1.14	1.40	
A2	2.03	2.79	
С	0.34	0.610	
D	9.65	10.67	
E	2.49	2.59	
E1	4.98	5.18	
F	0.508	1.016	
F1	1.14	1.78	
Н	14.71	16.51	
H1	5.84	6.795	
H2	8.40	9.00	
Н3	3.53	3.96	
H4	2.54	3.05	
L	12.70	14.22	
L1	-	6.35	

Mechanical Mounting Method	Maximum Torque / Pressure specification	
Screw through hole in package tab	1 Newton Meter (nm) or 8.8 inch-pounds (lb-in)	
Clamp against package body	12.3 kilogram-force per square centimeter (kgf/cm²) or 175 lbf/in²	

**Soldering time and temperature:** This product has been designed for use with high-temperature, lead-free solder. The component leads can be subjected to a maximum temperature of 300 °C, for up to 10 seconds. See Application Note AN-303, for more details.

# **Ordering Information**

Part Number	Package	Packing
QH20TZ625	TO-220AC	50 units/tube

The information contained in this document is subject to change without notice.



Revision	Notes	Date
1.0	Preliminary release.	05/22
1.1	Production release.	12/22



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